

# Recipe for AZ10XT resist

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## Application

Substrate preparation: it is preferable to process the silicon substrate by evaporation of HMDS at 150°C for 45 sec, using the Delta RC80. Before use, take the resist out of the fridge and leave it for 30 minutes to get to room temperature.

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|-------------------------|---|
| Tone                    | Positive                                  |
| Reference               | <a href="#">Microchemicals</a>            |
| Spin coat               | 8.3 $\mu\text{m}$ @2500 RPM               |
| Pre bake                | 3 min @110°C on hotplate                  |
| Rehydrate               | 30 min                                    |
| Exposure time           | Approx. ~24 sec @ 8.42 mW/cm <sup>2</sup> |
| Development             | 6 min in AZ400K (1:4)                     |
| Stopping of development | 30 sec in H <sub>2</sub> O                |

## Results

### Spin curve

